



**Microsemi Corp.**  
The diode experts

# 60S SERIES

SCOTTSDALE, AZ

For more information call:  
(602) 941-6300

## DESCRIPTION/FEATURES

- ECONOMICAL 6 AMP  $I_O$  MOLDED DEVICE OFFERS CAPABILITY OF STUD-MOUNTED RECTIFIERS
- 400 AMPS SURGE PROVIDES HIGH IN-RUSH CURRENT CAPABILITY
- WIDE VOLTAGE RANGE AVAILABLE: 50 TO 1000 VOLTS  $V_{RRM}$

## Major Ratings and Characteristics

	60S	
$I_F(AV)$	6	A
@ Max. $T_L$	95	$^{\circ}C$
$I_{FSM}$		
@ 50 Hz	382	A
@ 60 Hz	400	
$I^2t$		$A^2s$
@ 50 Hz	712	
@ 60 Hz	650	
$T_J$	-40 to 175	$^{\circ}C$
$V_{RRM}$ Range	50-1000	V

## VOLTAGE RATINGS

Part Number	Working $V_{RRM}$ (V)	$V_p$ - Max. Direct Reverse Voltage (V)
	$T_J = -40^{\circ}C$ to $200^{\circ}C$	$T_J = -40^{\circ}C$ to $200^{\circ}C$
60S05	50	50
60S1	100	100
60S2	200	200
60S4	400	400
60S5	500	500
60S6	600	600
60S8	800	800
60S10	1000	1000

## ELECTRICAL SPECIFICATIONS

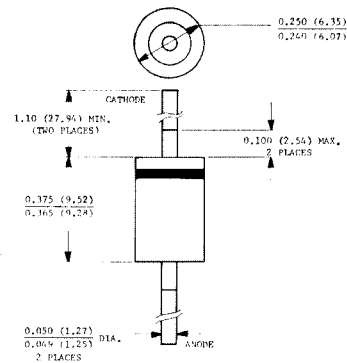
	60S	Units	Conditions
$I_F(AV)$ Max. average forward current	6	A	1 phase operation, 180 $^{\circ}$ conduction, $T_L = 95^{\circ}C$ , $\ell = 9.5$ mm (0.375 in.)
$I_{FSM}$ Max. peak one-cycle non-repetitive surge current	382	A	Half cycle 50 Hz sine wave or 6 ms rectangular pulse Following any rated load condition and with rated $V_{RRM}$ applied
	400		Half cycle 60 Hz sine wave or 5 ms rectangular pulse
	454		Half cycle 50 Hz sine wave or 6 ms rectangular pulse Following any rated load condition and with $V_{RRM}$ applied following surge = 0
	475		Half cycle 60 Hz sine wave or 5 ms rectangular pulse
$I^2t$ Max. $I^2t$ for fusing	712	$A^2s$	$t = 10$ ms With rated $V_{RRM}$ applied following surge, initial $T_J = 175^{\circ}C$
	650		$t = 8.3$ ms
	1006		$t = 10$ ms With $V_{RRM} = 0$ following surge, initial $T_J = 175^{\circ}C$
$I^2\sqrt{t}$ Max. $I^2\sqrt{t}$ for individual device fusing (1)	919	$A^2\sqrt{s}$	$t = 8.3$ ms
$I^2\sqrt{t}$ Max. $I^2\sqrt{t}$ for individual device fusing (1)	10 330	$A^2\sqrt{s}$	$t = 0.1$ to 10 ms, $V_{RRM} = 0$ following surge
$V_{FM}$ Max. peak forward voltage	100	V	$I_F(AV) = 6A$ (18.8A peak), $T_J = 25^{\circ}C$
$I_{R(AV)}$ Max. average reverse current	50 - 100V	mA	Max. rated $I_F(AV)$ and $V_{RRM}$ , $T_C = 95^{\circ}C$ , length of leads to the temperature measurement points (heat sinks) = 9.5 mm (0.375 in.)
	200V		
	400-500V		
	600-1000V		

## THERMAL-MECHANICAL SPECIFICATIONS

$T_J$ Max. operating junction temperature range	-40 to 175	$^{\circ}C$	
$T_{stg}$ Max. storage temperature range	-40 to 175	$^{\circ}C$	
$R_{thJC}$ Max. internal thermal resistance, junction-to-leads		deg C/W	DC operation, double side cooled, measured 9.5 mm (0.375 in.) from body
	Length of leads (1) (1/8") 3.2 mm		
$\theta$ Length of leads (1) (3/8") 9.5 mm	11.0		
Length of leads (1) (3/4") 19 mm	14.7	$\pm 10\%$	
	20.0		
wt. Approximate weight	1.5 (0.053)	g (oz)	

Note (1):  $I^2t$  for time  $t_x = I^2\sqrt{t} \cdot \sqrt{t_x}$

## 6 AMP AXIAL-LEAD SILICON RECTIFIER DIODES



All Dimensions in Inches and (Millimeters)

## MECHANICAL CHARACTERISTICS

CASE: Molded plastic use Flame Retardant Epoxy.

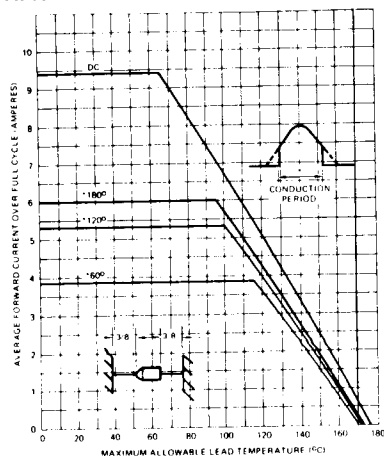
TERMINALS: Axial leads, solderable per MIL-STD-202, Method 208.

POLARITY: Color band denotes cathode.

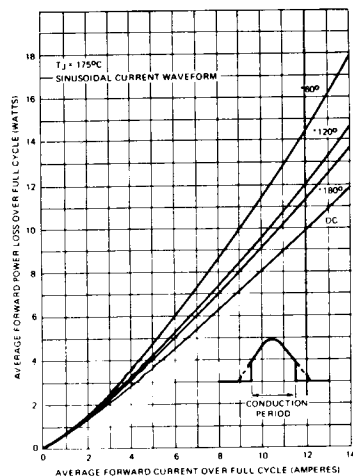
MOUNTING POSITION: Any.

# 60S Series

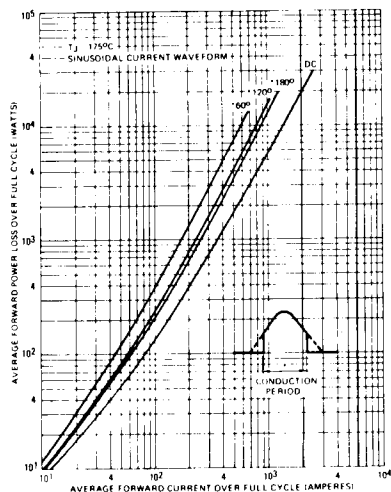
## RATING AND CHARACTERISTIC CURVES



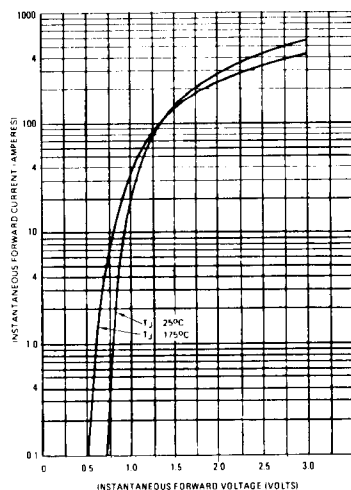
**Fig. 1 — Average Forward Current Vs. Lead Temperature at Heat Sinks**  
( $l = 3/8$  inch)



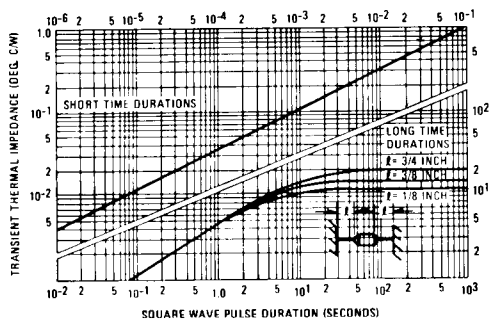
**Fig. 2 — Maximum Average Forward Power Loss Vs. Low-Level Average Forward Current**



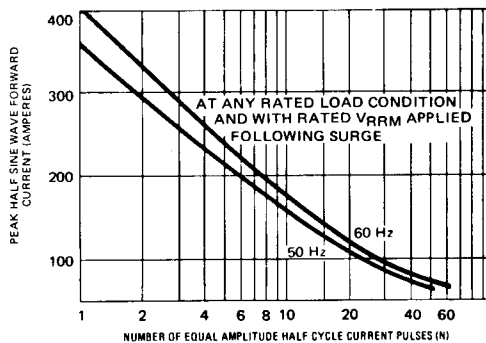
**Fig. 3 — Maximum Average Forward Power Loss Vs. High-Level Forward Current**



**Fig. 4 — Maximum Instantaneous Forward Voltage Vs. Instantaneous Forward Current**



**Fig. 5 — Maximum Transient Thermal Impedance, Vs. Square Wave Pulse Duration**



**Fig. 6 — Maximum Non-Repetitive Surge Current Vs. Number of Current Pulses**